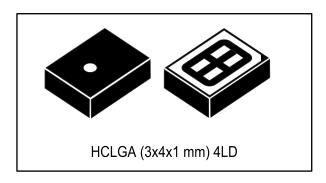
## **MP34DT01**



# MEMS audio sensor omnidirectional digital microphone

Datasheet - production data



#### **Features**

- Single supply voltage
- Low power consumption
- 120 dBSPL acoustic overload point
- 63 dB signal-to-noise ratio
- Omnidirectional sensitivity
- –26 dBFS sensitivity
- PDM output
- HCLGA package
  - Top-port design
  - SMD-compliant
  - EMI-shielded
  - ECOPACK<sup>®</sup>, RoHS, and "Green" compliant

### **Applications**

- Mobile terminals
- Laptop and notebook computers
- Portable media players
- VolP
- Speech recognition
- A/V eLearning devices
- Gaming and virtual reality input devices
- Digital still and video cameras
- Antitheft systems

### **Description**

The MP34DT01 is an ultra-compact, low-power, omnidirectional, digital MEMS microphone built with a capacitive sensing element and an IC interface.

The sensing element, capable of detecting acoustic waves, is manufactured using a specialized silicon micromachining process dedicated to produce audio sensors.

The IC interface is manufactured using a CMOS process that allows designing a dedicated circuit able to provide a digital signal externally in PDM format.

The MP34DT01 has an acoustic overload point of 120 dBSPL with a 63 dB signal-to-noise ratio and –26 dBFS sensitivity.

The MP34DT01 is available in a top-port, SMD-compliant, EMI-shielded package and is guaranteed to operate over an extended temperature range from -40 °C to +85 °C.

Table 1: Device summary

Order codes	Temp. range [°C]	Package	Packing
MP34DT01	-40 to +85	HCLGA (3x4 x1 mm) 4LD	Tray
MP34DT01TR	-40 to +85	HCLGA (3x4x1 mm) 4LD	Tape and reel

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MP34DT01 Pin description

# 1 Pin description

Figure 1: Pin connections

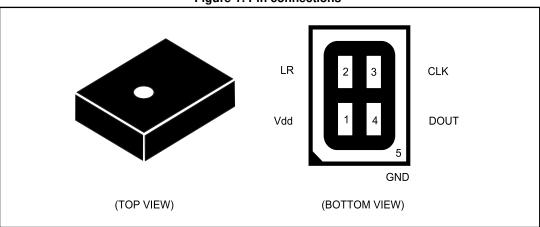


Table 2: Pin description

Pin #	Pin name	Function
1	Vdd	Power supply
2	LR	Left/Right channel selection
3	CLK	Synchronization input clock
4	DOUT	Left/Right PDM data output
5 (ground ring)	GND	0 V supply

## 2 Acoustic and electrical specifications

### 2.1 Acoustic and electrical characteristics

The values listed in the table below are specified for Vdd = 1.8 V, Clock = 2.4 MHz,  $T = 25 \,^{\circ}\text{C}$ , unless otherwise noted.

Table 3: Acoustic and electrical characteristics

Symbol	Parameter	Test condition	Min.	Typ. (1)	Max.	Unit
Vdd	Supply voltage		1.64	1.8	3.6	V
ldd	Current consumption in normal mode	Mean value		0.6		mA
IddPdn	Current consumption in power-down mode <sup>(2)</sup>			20		μΑ
Scc	Short-circuit current		1		10	mA
AOP	Acoustic overload point			120		dBSPL
So	Sensitivity		-29	-26	-23	dBFS
SNR	Signal-to-noise ratio	A-weighted at 1 kHz, 1 Pa		63		dB
PSR	Power supply rejection	Guaranteed by design		-70		dBFS
Clock	Input clock frequency (3)		1	2.4	3.25	MHz
Ton	Turn-on time (4)	Guaranteed by design			10	ms
Тор	Operating temperature range		-40		+85	°C
V <sub>IOL</sub>	Low-level logic input/output voltage	I <sub>out</sub> = 1 mA	-0.3		0.35xVdd	V
V <sub>IOH</sub>	High-level logic input/output voltage	I <sub>out</sub> = 1 mA	0.65xVdd		Vdd+0.3	V

#### Notes:

**Table 4: Distortion specifications** 

Parameter	Test condition	Value
Distortion	100 dBSPL (50 Hz - 4 kHz)	< 1% THD + N
Distortion	115 dBSPL (1 kHz)	< 5% THD + N

<sup>&</sup>lt;sup>(1)</sup>Typical specifications are not guaranteed.

<sup>(2)</sup> Input clock in static mode.

<sup>(3)</sup> Duty cycle: min = 40% max = 60%.

 $<sup>^{(4)}</sup>$ Time from the first clock edge to valid output data.

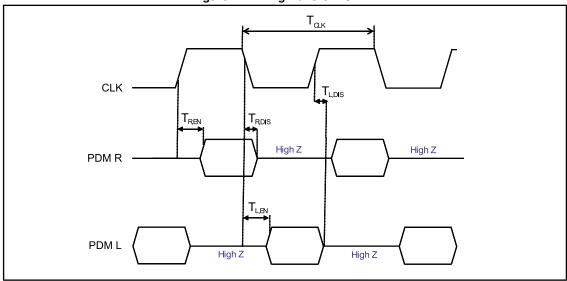
# 2.2 Timing characteristics

**Table 5: Timing characteristics** 

Parameter	Description	Min.	Max.	Unit
f <sub>CLK</sub>	Clock frequency for normal mode	1	3.25	MHz
f <sub>PD</sub>	Clock frequency for power-down mode		0.23	MHz
T <sub>CLK</sub>	Clock period for normal mode	308	1000	ns
T <sub>R,EN</sub>	Data enabled on DATA line, L/R pin = 1	18 <sup>(1)</sup>		ns
T <sub>R,DIS</sub>	Data disabled on DATA line, L/R pin = 1		16 <sup>(1)</sup>	ns
$T_{L,EN}$	Data enabled on DATA line, L/R pin = 0	18 <sup>(1)</sup>		ns
T <sub>L,DIS</sub>	Data disabled on DATA line, L/R pin = 0		16 <sup>(1)</sup>	ns

#### Notes:

Figure 2: Timing waveforms



<sup>&</sup>lt;sup>(1)</sup>From design simulations

### 2.3 Frequency response

Figure 3: Frequency response and mask

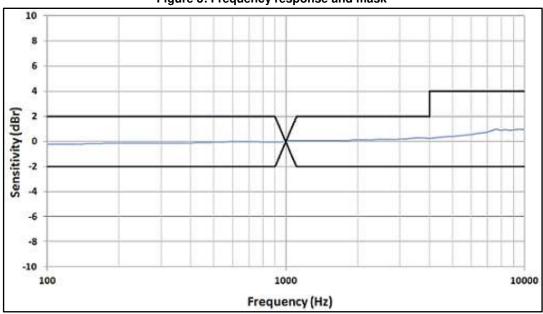


Table 6: Frequency response mask for digital microphones

Frequency / Hz (1)	Lower limit	Upper limit	Unit
1004000	-2	+2	dBr 1 kHz
400010000	-2	+4	dBr 1 kHz

#### Notes

 $^{(1)}At~T$  = 20 °C and acoustic stimulus = 1 Pa (94 dB SPL)

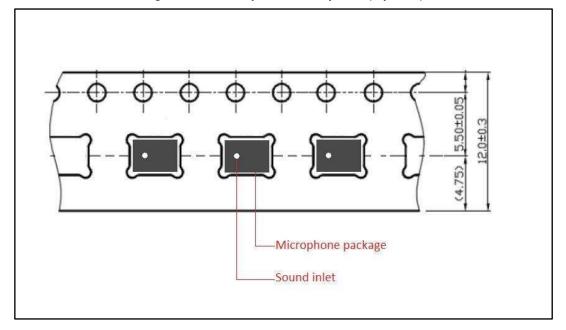
#### **Carrier tape mechanical specifications** 3

**∆**2.0±0.1 1.0±0.05 Ø1.55±0.05 0.3±0.05 8.0±0.1 ø1.55±0.05 SECTION B-B (10/1)

Figure 4: Carrier tape without microphone (top view)

Figure 5: Carrier tape with microphone (top view)

SECTION A-A (10/1)



#### 4 Process recommendations

To ensure a consistent manufacturing process it is strongly advised to comply with the following recommendations:

- The recommended pick-up area for the MP34DT01 package must be defined using the worst case (ie. no device alignment during the picking process). This area has been defined considering all the tolerances of the components involved (reel, package, sound inlet). The picker tolerance shall be considered as well.
- To prevent damage to the MEMS membrane or incorrect pick-up and placement, do not pick up the component on the inlet area
- For the package outline please refer to Figure 5: "Carrier tape with microphone (top view)". Nozzle shape, size, and placement accuracy are the other key factors to consider when deciding on the coordinates for picking.
- Device alignment before picking is highly recommended.
- A vacuum force greater than 7 psi must be avoided
- 1 kPa = 0.145 psi (lb/in2) = 0.0102 kgf/cm<sup>2</sup> = 0.0098 atm
- All recommended dimensions (device safe-picking area) do not include the pick-andplace equipment tolerances

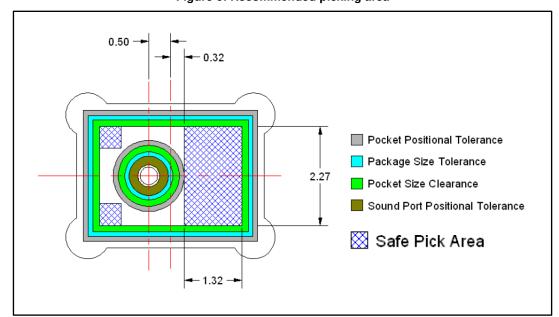


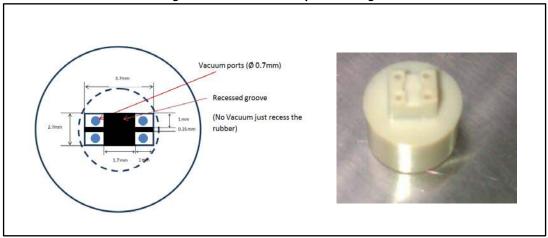
Figure 6: Recommended picking area

To have a safe pick-up "by design", ST strongly advises an ad hoc nozzle.

The following picker ensures that the holes for the vacuum and the air stream are ALWAYS away from the porthole of the device (4 vacuum ports located at each corner of the device).

The recommended nozzle also has a recess, in the form of a cross, which guarantees that the porthole is always left at atmospheric pressure. By using the recommended nozzle, the membrane will not suffer any sudden air disturbances during the picking or placing of the devices in the tape and reel.

Figure 7: Recommended picker design





Sensing element MP34DT01

# 5 Sensing element

The sensing element shall mean the acoustic sensor consisting of a conductive movable plate and a fixed plate placed in a tiny silicon chip. This sensor transduces the sound pressure into the changes of coupled capacity between those two plates.

Omron Corporation supplies this element for STMicroelectronics.

#### **Absolute maximum ratings** 6

Stresses above those listed as "absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device under these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 7: Absolute maximum ratings

Symbol	Ratings	Maximum value	Unit
Vdd	Supply voltage	-0.3 to 6	٧
Vin	Input voltage on any control pin	-0.3 to Vdd +0.3	V
T <sub>STG</sub>	Storage temperature range	-40 to +125	°C
ESD	Electrostatic discharge protection	2 (HBM)	kV



This device is sensitive to mechanical shock, improper handling can cause permanent damage to the part.



This device is sensitive to electrostatic discharge (ESD), improper handling can cause permanent damage to the part.



Functionality MP34DT01

# 7 Functionality

### 7.1 L/R channel selection

The L/R digital pad lets the user select the DOUT signal pattern as shown in *Table 8: "L/R channel selection"*. The L/R pin must be connected to Vdd or GND.

Table 8: L/R channel selection

L/R	CLK low	CLK high
GND	Data valid	High impedance
Vdd	High impedance	Data valid

MP34DT01 Package information

### 8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

### 8.1 Soldering information

The HCLGA (3 x 4) 4LD package is also compliant with the RoHS and "Green" standards and is qualified for soldering heat resistance according to JEDEC J-STD-020.

Land pattern and soldering recommendations are available at www.st.com.

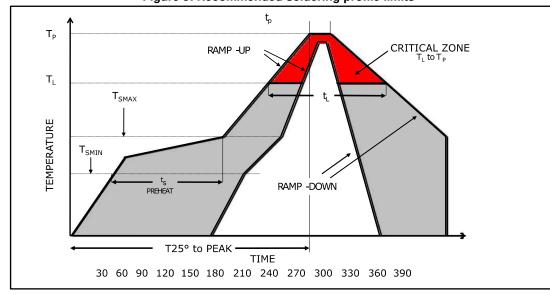


Figure 8: Recommended soldering profile limits

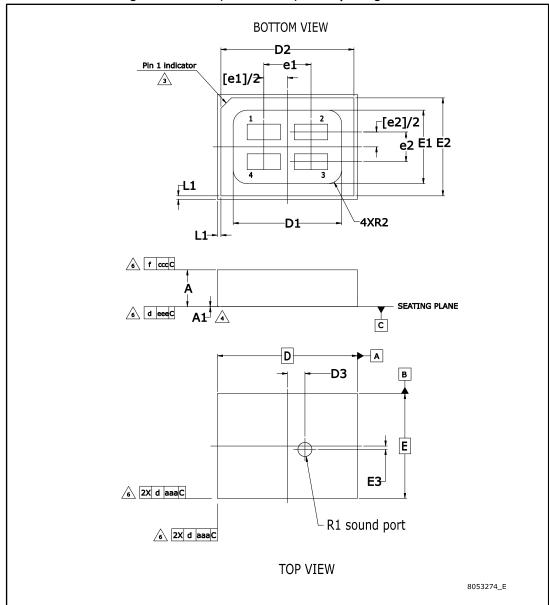
Table 9: Recommended soldering profile limits

Description	Parameter	Pb free
Average ramp rate	$T_L$ to $T_P$	3 °C/sec max
Preheat  Minimum temperature  Maximum temperature  Time (T <sub>SMIN</sub> to T <sub>SMAX</sub> )	T <sub>SMIN</sub> T <sub>SMAX</sub> t <sub>S</sub>	150 °C 200 °C 60 sec to 120 sec
Ramp-up rate	T <sub>SMAX</sub> to T <sub>L</sub>	
Time maintained above liquids temperature Liquids temperature	t <sub>L</sub> T <sub>L</sub>	60 sec to 150 sec 217 °C
Peak temperature	T <sub>P</sub>	260 °C max
Time within 5 °C of actual peak temperature		20 sec to 40 sec
Ramp-down rate		6 °C/sec max
Time 25 °C (t25 °C) to peak temperature		8 minutes max

Package information MP34DT01

## 8.2 HCLGA package information

Figure 9: HCLGA (3 x 4 x 1 mm) 4-lead package outline

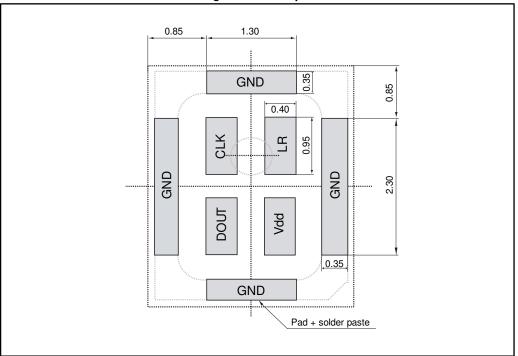


Note: The MEMS microphone plastic cap can exhibit some level of variation in color when the device is subjected to thermal processes.

Table 10: HCLGA (3 x 4 x 1 mm) 4-lead package dimensions

Symbol	mm		
	Min.	Тур.	Max.
A	0.90	1.00	1.10
A1	0.00	-	0.05
b	0.35	0.45	0.50
D	3.90	4.00	4.10
D1	3.05	3.10	3.15
D2	3.75	3.80	3.85
D3	0.30	0.50	0.70
E	2.90	3.00	3.10
E1	2.05	2.10	2.15
E2	2.75	2.80	2.85
E3	-0.20	0.00	0.20
e1	1.30	1.35	1.40
e2	0.80	0.85	0.90
h	0.25	0.30	0.35
L	0.90	0.95	1.00
L1	-	0.10	-
N	4		
R1	0.30	0.40	0.50
R2	-	0.40	-
aaa	0.15		
ccc	0.10		
eee	0.08		

Figure 10: Land pattern



MP34DT01 Revision history

# 9 Revision history

Table 11: Document revision history

Date	Revision	Changes		
06-Oct-2011	1	Initial release		
18-Nov-2011	2	Removed "stereo" from title, Section "Features", and Section "Description"		
29-Nov-2011	3	Updated Section "Features" and Section "Description"		
04-Jan-2012	4	Updated Added So limits to <i>Table 3: "Acoustic and electrical characteristics"</i> Minor textual updates		
23-Mar-2012	5	Updated Figure 9: "HCLGA (3 x 4 x 1 mm) 4-lead package outline"  Pin 1 indicator removed from top view of package on page 1 and Figure 1: "Pin connections"  Updated Table 10: "HCLGA (3 x 4 x 1 mm) 4-lead package dimensions"		
06-Apr-2012	6	Updated maximum supply voltage in <i>Table 3: "Acoustic and electrical characteristics"</i>		
07-May-2012	7	Added V <sub>IOL</sub> , V <sub>IOH</sub> to Table 3: "Acoustic and electrical characteristics"		
18-May-2012	8	Updated Table 5: "Timing characteristics"		
05-Jul-2012	9	Added Section 5: "Sensing element"  Added Figure 10: "Land pattern"  Updated temperature range to -40 to +85 °C throughout datasheet		
21-Feb-2013	10	Updated dimension T2 in Table 10: "HCLGA (3 x 4 x 1 mm) 4-lead package dimensions"		
07-Jun-2013	11	Updated - Figure 3: "Frequency response and mask" - Table 6: "Frequency response mask for digital microphones" - HCLGA mechanical data Figure 9: "HCLGA (3 x 4 x 1 mm) 4-lead package outline" and Table 10: "HCLGA (3 x 4 x 1 mm) 4-lead package dimensions" Added - Section 3: "Carrier tape mechanical specifications" - Section 4: "Process recommendations"		
27-Feb-2015	12	Minor textual updates Added note below Figure 9: "HCLGA (3 x 4 x 1 mm) 4-lead package outline"		

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